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FAIRCHILD

80V N-Channel PowerTrench[®] MOSFET

General Description

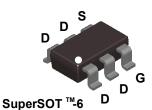
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.

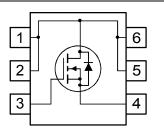
Applications

DC/DC converter

Features

- 3.0 A, 80 V $R_{DS(ON)} = 77 \text{ m}\Omega @ V_{GS} = 10 \text{ V}$ $R_{DS(ON)} = 88 \text{ m}\Omega @ V_{GS} = 6 \text{ V}$
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- Low gate charge (13nC typ)
- High power and current handling capability
- Fast switching speed





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		80	V
V _{GSS}	Gate-Source Voltage		± 20	V
I _D	Drain Current – Continuous	(Note 1a)	3.0	А
	– Pulsed		20	
P _D	Maximum Power Dissipation	(Note 1a)	1.6	W
		(Note 1b)	0.8	
T _J , T _{STG}	Operating and Storage Junction Temperat	ure Range	–55 to +150	°C
Therma	I Characteristics			
D	Thermal Registeres, Junction to Ambient	(1)-1-(-)	70	°C/M

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
R _{θJC}	Thermal Resistance, Junction-to-Case	(Note 1)	30	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
.352	FDC3512	7"	8mm	3000 units

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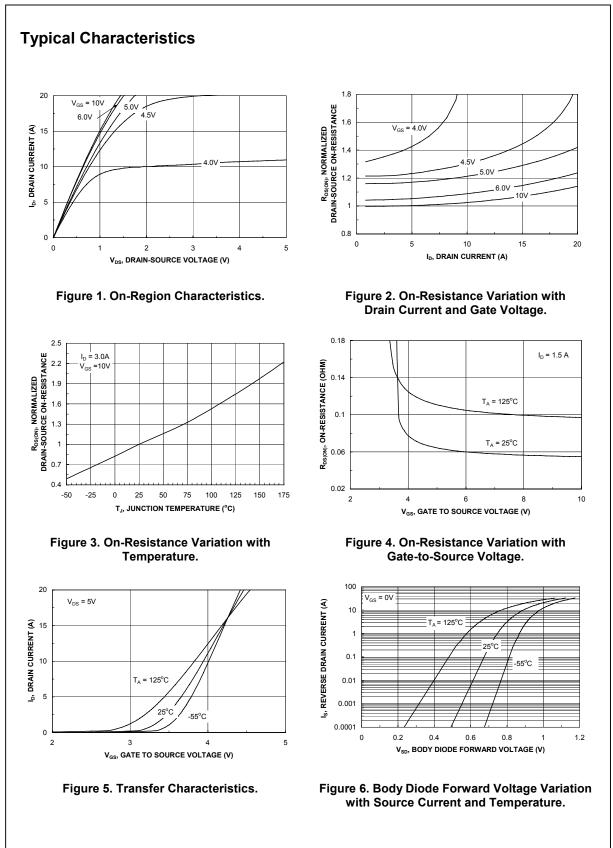
	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	urce Avalanche Ratings (Note	2)				<u> </u>
N _{DSS}	Drain-Source Avalanche Energy	Single Pulse, V_{DD} = 40 V, I_D =3.0 A			90	mJ
AR	Drain-Source Avalanche Current				3.0	Α
Off Char	acteristics	•				
BV _{DSS}	Drain–Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	80			V
Δ <u>BV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		80		mV/°C
DSS	Zero Gate Voltage Drain Current	V _{DS} = 64 V, V _{GS} = 0 V			1	μA
GSSF	Gate-Body Leakage, Forward	V _{GS} = 20 V, V _{DS} = 0 V			100	nA
GSSR	Gate–Body Leakage, Reverse	V _{GS} = -20 V, V _{DS} = 0 V			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250 μA	2	2.4	4	V
$\Delta V_{GS(th)}$ ΔT_J	Gate Threshold Voltage Temperature Coefficient	I_D = 250 µA, Referenced to 25°C		-6		mV/°C
R _{DS(on)}	Static Drain–Source On Resistance	$ \begin{array}{l} V_{GS} = 10 \ V, \ I_D = 3.0 \ A \\ V_{GS} = 6.0 \ V, \ I_D = 2.8 \ A \\ V_{GS} = 10 \ V, \ I_D = 3.0 \ A; T_J = 125^{\circ}C \end{array} $		56 61 97	77 88 141	mΩ
D(on)	On–State Drain Current	V _{GS} = 10 V, V _{DS} = 5 V	10			Α
GFS	Forward Transconductance	V _{DS} = 10 V, I _D = 3.0 A		14		S
Dvnamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 40 V$, $V_{GS} = 0 V$,		634		pF
Coss	Output Capacitance	f = 1.0 MHz		58		pF
Crss	Reverse Transfer Capacitance			28		pF
Switchin	g Characteristics (Note 2)					
d(on)	Turn–On Delay Time	$V_{DD} = 40 V$, $I_D = 1 A$,		7	14	ns
t _r	Turn–On Rise Time	$V_{GS} = 10 V$, $R_{GEN} = 6 \Omega$		3	6	ns
d(off)	Turn–Off Delay Time			24	28	ns
f	Turn–Off Fall Time			4	8	ns
Q _g	Total Gate Charge	$V_{DS} = 40 V$, $I_{D} = 3.0 A$,		13	18	nC
Q _{gs}	Gate–Source Charge	V _{GS} = 10 V		2.4		nC
Q _{gd}	Gate-Drain Charge			2.8		nC
Drain–So	ource Diode Characteristics	and Maximum Ratings				
s	Maximum Continuous Drain-Source				1.3	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = 1.3 A$ (Note 2)		0.8	1.2	V
r) rr	Diode Reverse Recovery Time Diode Reverse Recovery Charge	I _F = 3.0 A, d _i F/d _t = 300 A/μs (Note 2)		28.2 48		nS nC

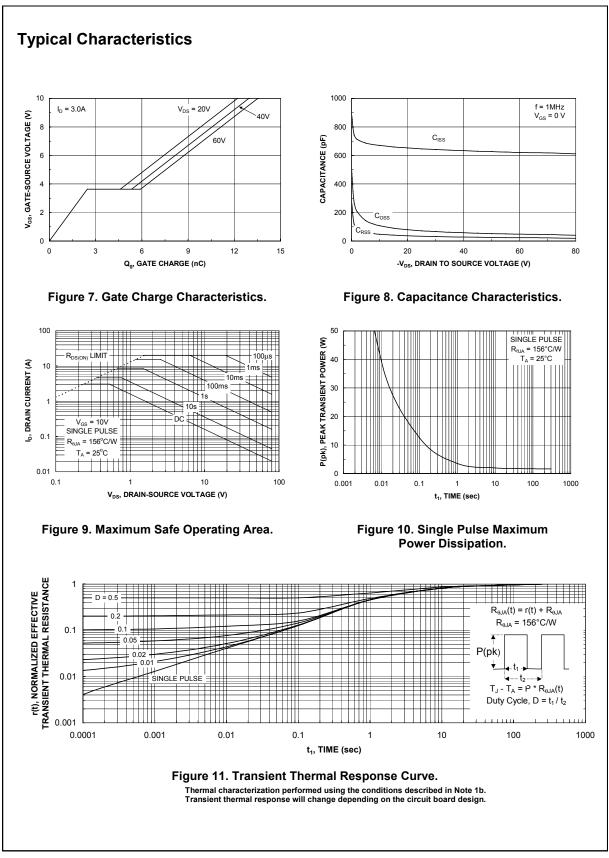
 $R_{0,A}$ is the sum of the junction to use and use to unknown restance that is a probability of the user's board design.

a. $~78^\circ\text{C/W}$ when mounted on a 1in^2 pad of 2oz copper on FR-4 board.

b. $156^{\circ}C/W$ when mounted on a minimum pad.

2. Pulse Test: Pulse Width $\leq 300~\mu s,~\text{Duty}~\text{Cycle} \leq 2.0\%$





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